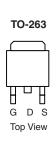


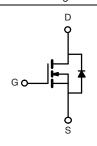
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Vishay Siliconix

Automotive N-Channel 100 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	100				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0105				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 \text{ V}$	0.0120				
I _D (A)	100				
Configuration	Single				





N-Channel MOSFET

FEATURES

- TrenchFET® Power MOSFET
- Package with Low Thermal Resistance
- AEC-Q101 Qualified^d
- 100 % R_g and UIS Tested
- Material categorization:
 For definitions of compliance please see www.vishay.com/doc?99912





ORDERING INFORMATION	
Package	TO-263
Lead (Pb)-free and Halogen-free	SQM100N10-10-GE3

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V_{DS}	100	V	
Gate-Source Voltage		V_{GS}	± 20	V	
Continuous Drain Current	T _C = 25 °C ^a	l _D	100		
Continuous Drain Current	T _C = 125 °C		70		
Continuous Source Current (Diode Conduc	I _S	100	А		
Pulsed Drain Current ^b		I _{DM}		400	
Single Pulse Avalanche Current		I _{AS}	75		
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	280	mJ	
Maximum Dawar Dissipationh	T _C = 25 °C	D	375	W	
Maximum Power Dissipation ^b	T _C = 125 °C	P_{D}	125	VV	
Operating Junction and Storage Temperation	ure Range	T _J , T _{stg}	- 55 to + 175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount ^c	R_{thJA}	40	°C \\\\	
Junction-to-Case (Drain)		R_{thJC}	0.4	°C/W	

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.



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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT		
Static								
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		100	-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$		2.0	2.5	V	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	± 100	nA	
		V _{GS} = 0 V	V _{DS} = 100 V	-	-	1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 100 V, T _J = 125 °C	-	-	50	μΑ	
		V _{GS} = 0 V	V _{DS} = 100 V, T _J = 175 °C	-	-	500		
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	120	-	-	Α	
		V _{GS} = 10 V	I _D = 30 A	-	0.0070	0.0105	Ω	
Durin On the Oracle Business and		V _{GS} = 10 V	I _D = 30 A, T _J = 125 °C	-	-	0.0200		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 30 A, T _J = 175 °C	-	-	0.0260		
		V _{GS} = 4.5 V	I _D = 20 A	-	0.0080	0.0120		
Forward Transconductanceb	9 _{fs}	V _{DS} = 15 V, I _D = 30 A		-	115	-	S	
Dynamic ^b					•		,	
Input Capacitance	C _{iss}				6440	8050		
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	655	820	pF	
Reverse Transfer Capacitance	C _{rss}	1		-	315	395		
Total Gate Charge ^c	Q_g			-	122	185	nC	
Gate-Source Charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 50 \text{ V}, I_D = 85 \text{ A}$	-	23	-		
Gate-Drain Charge ^c	Q_{gd}	1		-	28	-		
Gate Resistance	R_g	f = 1 MHz		0.70	1.41	2.30	Ω	
Turn-On Delay Time ^c	t _{d(on)}				13	20		
Rise Time ^c	t _r	$V_{DD} = 50 \text{ V}, \text{ R}_{L} = 0.6 \Omega$ $I_{D} \cong 85 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_{g} = 2.5 \Omega$		-	14	21	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	44	66		
Fall Time ^c	t _f			-	10	15		
Source-Drain Diode Ratings and Chara	acteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	400	Α	
Forward Voltage	V _{SD}	I _F = 85 A, V _{GS} = 0 V		-	0.9	1.5	V	

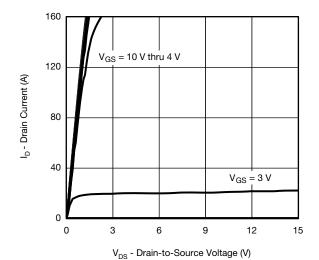
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,\,duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

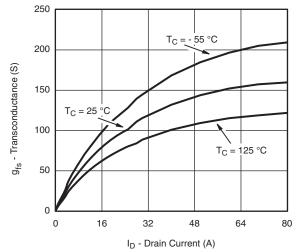
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



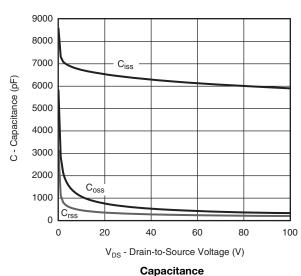
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

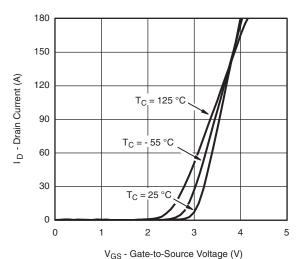


Output Characteristics



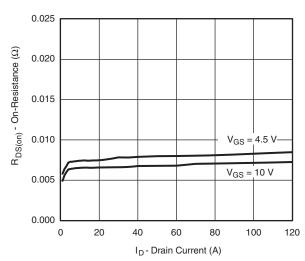
Transconductance



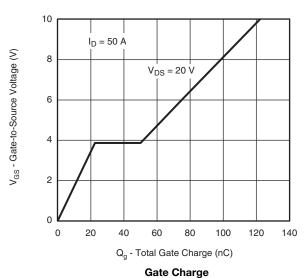


VGS - Gale-10-Source Vollage (V)

Transfer Characteristics



On-Resistance vs. Drain Current

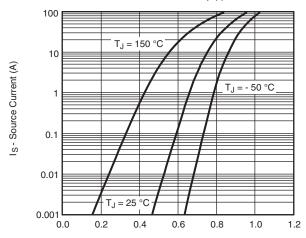


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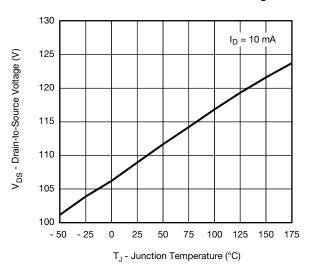
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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

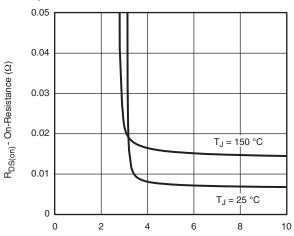


V_{SD} - Source-to-Drain Voltage (V)

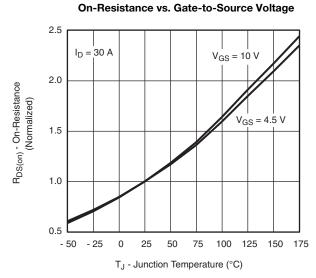
Source Drain Diode Forward Voltage



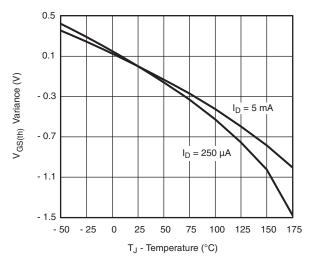
Breakdown Voltage vs. Junction Temperature



 V_{GS} - Gate-to-Source Voltage (V)

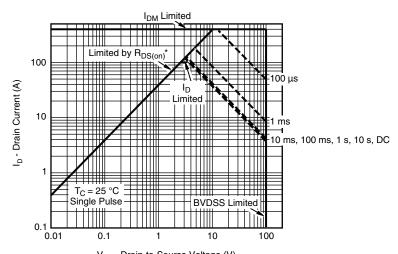


Normalized On-Resistance vs. Junction Temperature



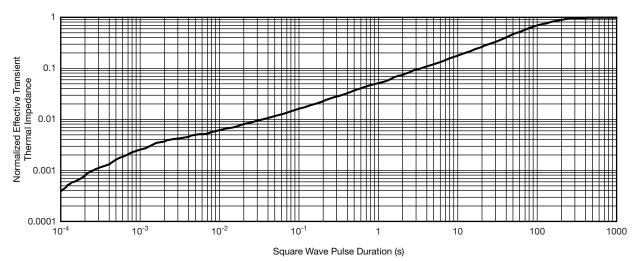
Threshold Voltage Variance vs. Junction Temperature

THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



 $\rm V_{DS}$ - Drain-to-Source Voltage (V) * V $_{GS}$ > minimum V $_{GS}$ at which R $_{DS(on)}$ is specified

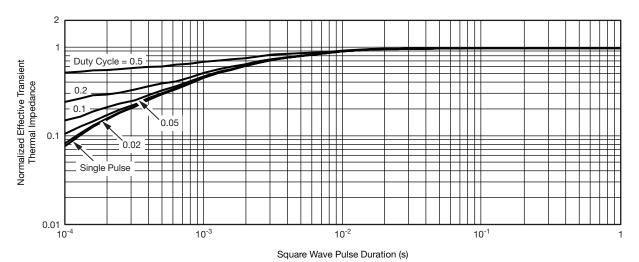
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

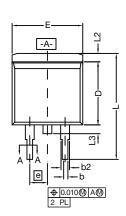
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

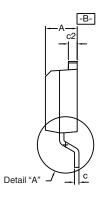
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

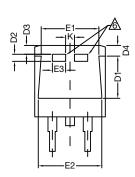
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?67027.



TO-263 (D²PAK): 3-LEAD

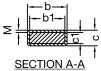








DETAIL A (ROTATED 90°)



_ - b1 	
≥ 	- -

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6. This feature is for thick lead.

		INCHES		MILLIMETERS		
DIM.		MIN.	MAX.	MIN. MAX.		
Α		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
c*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
D2		0.038	0.042	0.965	1.067	
D3		0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	Е	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	=	
	E2	0.355	0.375	9.017	9.525	
	E3	0.072	0.078	1.829	1.981	
	е	0.100) BSC	2.54 BSC		
	K	0.045	0.055	1.143	1.397	
	L	0.575	0.625	14.605	15.875	
	L1	0.090	0.110	2.286	2.794	
	L2	0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
	L4	0.010 BSC		0.254 BSC		
	М	-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13						

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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